

1 Gbps to 4.25 Gbps Limiting Amplifier With LOS and RSSI

FEATURES

- Multi-Rate Operation from 1 Gbps up to 4.25 Gbps
- 89-mW Power Consumption
- Input Offset Cancellation
- High Input Dynamic Range
- Output Disable
- CML Data Outputs
- Receive Signal Strength Indicator (RSSI)
- Loss of Signal Detection

- Polarity Select

- Single 3.3-V Supply

- Surface Mount Small Footprint 3-mm × 3-mm 16-Pin QFN Package

APPLICATIONS

- Cable Driver and Receiver
- 1.0625 Gbps, 2.125 Gbps, and 4.25 Gbps Fibre Channel Receivers
- Gigabit Ethernet Receivers

DESCRIPTION

The ONET4251PA is a versatile high-speed limiting amplifier for copper cable and fiber optic applications with data rates up to 4.25 Gbps.

This device provides a gain of about 50 dB, which ensures a full 800-mV_{p-p} differential output swing over its wide input signal dynamic range.

The high input signal dynamic range ensures low jitter output signals even when overdriven with input signal swings as high as 1200 mV_{p-p}.

The ONET4251PA comprises a loss of signal detection as well as a received signal strength indicator.

The part is available in a small footprint 3-mm × 3-mm 16-pin QFN package. It requires a single 3.3-V supply.

This power efficient limiting amplifier dissipates less than 89 mW typical. It is characterized for operation from -40°C to 85°C .

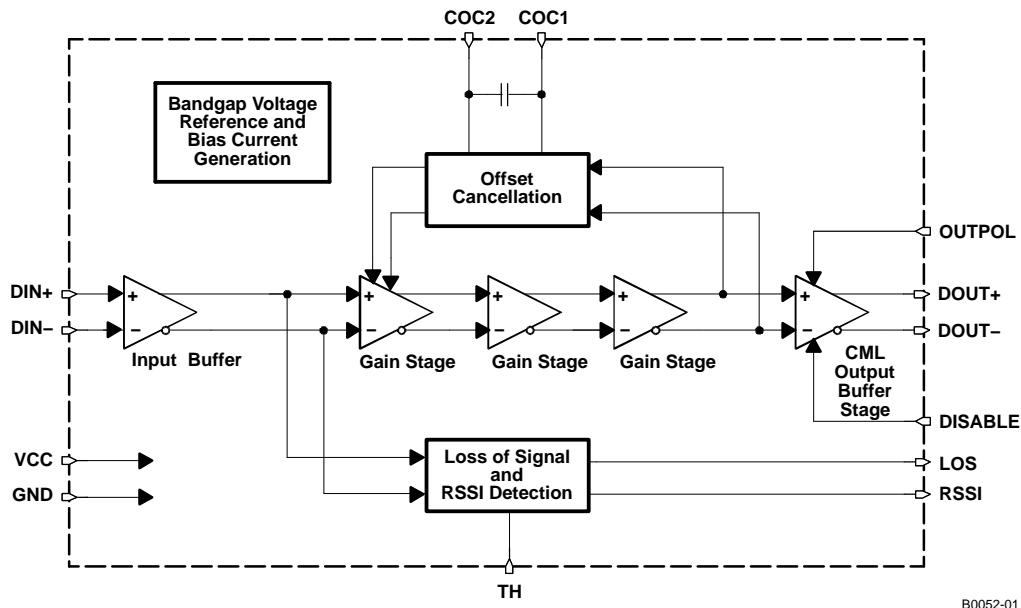
BLOCK DIAGRAM

A simplified block diagram of the ONET4251PA is shown in [Figure 1](#).

This compact 3.3 V, low power 4.25 Gbps limiting amplifier consists of a high-speed data path with offset cancellation block, a loss of signal and RSSI detection block, and a bandgap voltage reference and bias current generation block.



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B0052-01

Figure 1. Simplified Block Diagram of the ONET4251PA

HIGH SPEED DATA PATH

The high-speed data signal is applied to the data path by means of the input signal pins **DIN+/**DIN-****. The data path consists of the input stage with $2 \times 50\text{-}\Omega$ on-chip line termination to **VCC**, three gain stages, which provide the required typical gain of about 50 dB, and a CML output stage. The amplified data output signal is available at the output pins **DOUT+/**DOUT-****, which provide $2 \times 50\text{-}\Omega$ back-termination to **VCC**. The output stage also includes a data polarity switching function, which is controlled by the **OUTPOL** input, and a disable function, controlled by the signal applied to the **DISABLE** input pin.

An offset cancellation compensates for internal offset voltages and thus ensures proper operation even for very small input data signals.

The low frequency cutoff is typically as low as 50 kHz with the built-in filter capacitor.

For applications which require even lower cutoff frequencies, an additional external filter capacitor may be connected to the **COC1/COC2** pins.

LOSS OF SIGNAL AND RSSI DETECTION

The output signal of the input buffer is monitored by the loss of signal and RSSI detection circuitry. In this block, a signal is generated that is linear proportional to the input amplitude over a wide input voltage range. This signal is available at the **RSSI** output pin.

Furthermore, this circuit block compares the input signal to a threshold which can be programmed by means of an external resistor connected to the **TH** pin. If the input signal falls below the specified threshold, a loss of signal is indicated at the **LOSS** pin.

The relation between the **LOSS** assert voltage V_{AST} (in $\text{mV}_{\text{p-p}}$) and the external resistor R_{TH} (in $\text{k}\Omega$) connected to the **TH** pin can be approximated as given below:

$$R_{TH} \approx \frac{22.4 \text{ k}\Omega}{\left(V_{AST}/\text{mV}_{p-p} - 1\right)} + 560 \Omega \quad (1)$$

$$V_{AST} \approx \frac{22.4 \text{ mV}_{p-p}}{R_{TH}/\text{k}\Omega - 0.56} + 1 \text{ mV}_{p-p} \quad (2)$$

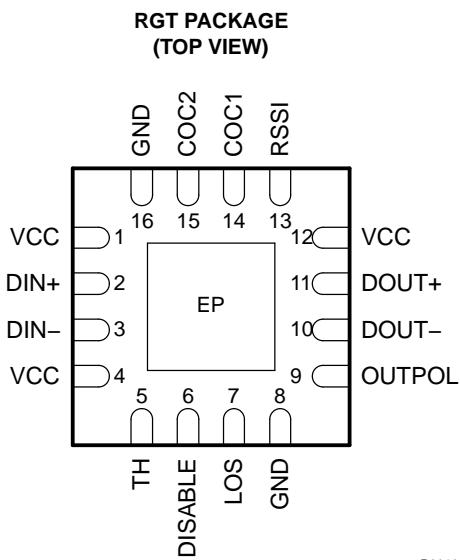
BANDGAP VOLTAGE AND BIAS GENERATION

The ONET4251PA limiting amplifier is supplied by a single 3.3-V $\pm 10\%$ supply voltage connected to the VCC pins. This voltage is referred to ground (GND).

An on-chip bandgap voltage circuitry generates a supply voltage independent reference from which all other internally required voltages and bias currents are derived.

PACKAGE

For the ONET4251PA a small footprint 3-mm \times 3-mm 16-pin QFN package, with a lead pitch of 0.5 mm is used. The pin out is shown in [Figure 2](#).



P0019-01

Figure 2. Pinout of ONET4251PA in a 3 mm x 3 mm 16-Pin QFN Package (Top View)

TERMINAL FUNCTIONS

TERMINAL	TYPE	DESCRIPTION
NO.		
1, 4, 12	VCC	supply
2	DIN+	analog-in
3	DIN-	analog-in
5	TH	analog-in
6	DISABLE	CMOS-in
7	LOS	CMOS-out
8, 16, EP	GND	supply
9	OUTPOL	CMOS-in
10	DOUT-	CML-out
11	DOUT+	CML-out

TERMINAL FUNCTIONS (continued)

TERMINAL NO.	NAME	TYPE	DESCRIPTION
13	RSSI	analog-out	Analog output voltage proportional to the input data amplitude. Indicates the strength of the received signal (RSSI).
14	COC1	analog	Offset cancellation filter capacitor terminal 1. Connect an additional filter capacitor between this pin and COC2 (pin 15). To disable the offset cancellation loop connect COC1 and COC2 (pins 14 and 15).
15	COC2	analog	Offset cancellation filter capacitor terminal 2. Connect an additional filter capacitor between this pin and COC1 (pin 14). To disable the offset cancellation loop connect COC1 and COC2 (pins 14 and 15).

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		VALUE/UNIT
V_{CC}	Supply voltage ⁽²⁾	−0.3 V to 4 V
V_{DIN+}, V_{DIN-}	Voltage at DIN+, DIN− ⁽²⁾	0.5 V to 4 V
$V_{TH}, V_{DISABLE}, V_{LOS}, V_{OUTPOL}, V_{DOUT+}, V_{DOUT-}, V_{RSSI}, V_{COC1}, V_{COC2}$	Voltage at TH, DISABLE, LOS, OUTPOL, DOUT+, DOUT−, RSSI, COC1, COC2 ⁽²⁾	−0.3 V to 4 V
$V_{COC,DIFF}$	Differential voltage between COC1 and COC2	±1 V
$V_{DIN,DIFF}$	Differential voltage between DIN+ and DIN−	±2.5 V
I_{LOS}	Current into LOS	−1 to 9 mA
$I_{DIN+}, I_{DIN-}, I_{DOUT+}, I_{DOUT-}$	Continuous current at inputs and outputs	−25 mA to 25 mA
ESD	ESD rating at all pins	2 kV (HBM)
$T_{J(max)}$	Maximum junction temperature	125°C
T_{STG}	Storage temperature range	−65 to 85°C
T_A	Characterized free-air operating temperature range	−40 to 85°C
T_{LEAD}	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

RECOMMENDED OPERATING CONDITIONS

		MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage	3.0	3.3	3.6	V
T_A	Operating free-air temperature	−40		85	°C
V_{IH}	CMOS input high voltage	2.1			V
V_{IL}	CMOS input low voltage			0.6	V

DC ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage	3	3.3	3.6	V
I_{VCC}	Supply current	<i>DISABLE</i> = low (excludes CML output current)	27	40	mA
V_{OD}	Differential data output voltage swing	<i>DISABLE</i> = high	0.25	10	mV_{p-p}
		<i>DISABLE</i> = low	600	760	
R_{IN}, R_{OUT}	Data input/output resistance	Single-ended	50		Ω
V_{RSSI}	RSSI output voltage	Input = 8 mV_{p-p} , $R_{RSSI} \geq 10 k\Omega$	180		mV
		Input = 80 mV_{p-p} , $R_{RSSI} \geq 10 k\Omega$	1900		
RSSI Linearity		$8 mV_{p-p} \leq V_{IN} \leq 80 mV_{p-p}$	$\pm 3\%$		
$V_{IN(MIN)}$	Minimum data input voltage			50	mV_{p-p}
$V_{IN(MAX)}$	Data input overload		1200		mV_{p-p}
LOS high voltage	$I_{SOURCE} = 30 \mu A$		2.4		V
LOS low voltage	$I_{SINK} = 1 mA$			0.4	V

AC ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted), typical operating condition is at $V_{CC} = 3.3$ V and $T_A = 25^\circ C$

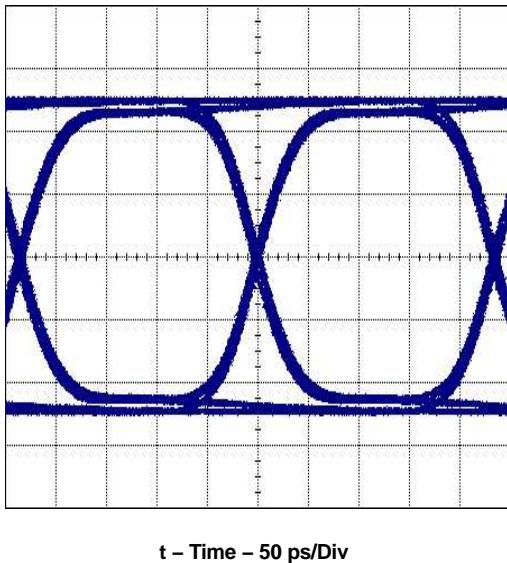
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Low frequency -3 dB bandwidth	$C_{OC} = \text{open}$		50		kHz
	$C_{OC} = 0.1 \mu F$		0.8		
Data rate		4.25			Gb/s
V_{NI}	Input referred noise		230		μV_{RMS}
DJ	Deterministic jitter	K28.5 pattern at 4.25 Gbps	6	19	ps_{p-p}
		K28.5 pattern at 2.125 Gbps	8	22	
		K28.5 pattern at 1.0625 Gbps	11	28	
RJ	Random jitter	Input = 50 mV_{pp}	1		ps_{RMS}
t_r	Output rise time	20% to 80%	35	70	ps
t_f	Output fall time	20% to 80%	35	70	ps
LOS hysteresis		K28.5 pattern at 4.25 Gbps	2.5	4.5	dB
R_{TH}	LOS threshold adjustment resistor	See (1)		4	$k\Omega$
V_{AST}	LOS assert voltage	$R_{TH} = 4 k\Omega$ K28.5 pattern at 4.25 Gbps	3	7	mV_{p-p}
V_{DEA}	LOS deassert voltage	$R_{TH} = 4 k\Omega$ K28.5 pattern at 4.25 Gbps		11	mV_{p-p}
t_{LOS}	LOS assert/deassert time		2	100	μs
t_{DIS}	Disable response time			20	ns

(1) For a given external resistor connected to the TH pin, the LOS assert voltage value may vary due to part-to-part variations. If high precision is required, adjustment of this resistor for each device is mandatory.

TYPICAL CHARACTERISTICS

Typical operating condition is at $V_{CC} = 3.3$ V and $T_A = 25^\circ\text{C}$ (unless otherwise noted).

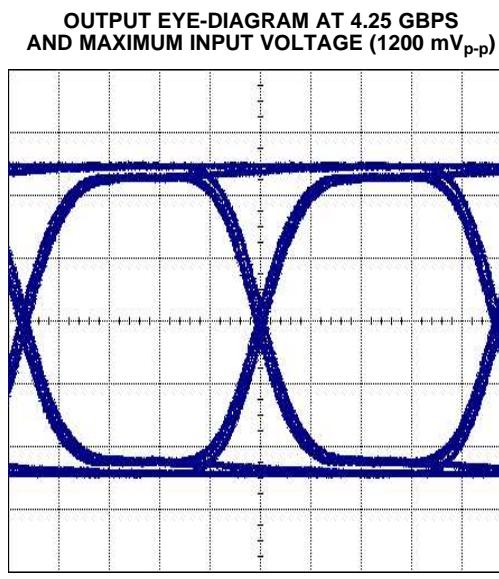
V_{OD} – Differential Output Voltage – 160 mV/Div



G005

Figure 3.

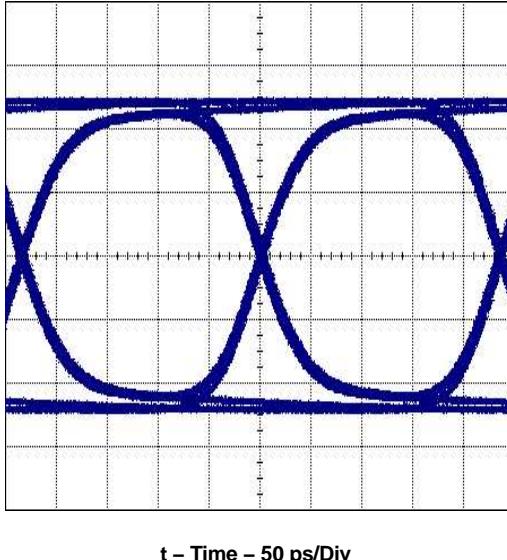
V_{OD} – Differential Output Voltage – 160 mV/Div



G006

Figure 4.

V_{OD} – Differential Output Voltage – 160 mV/Div

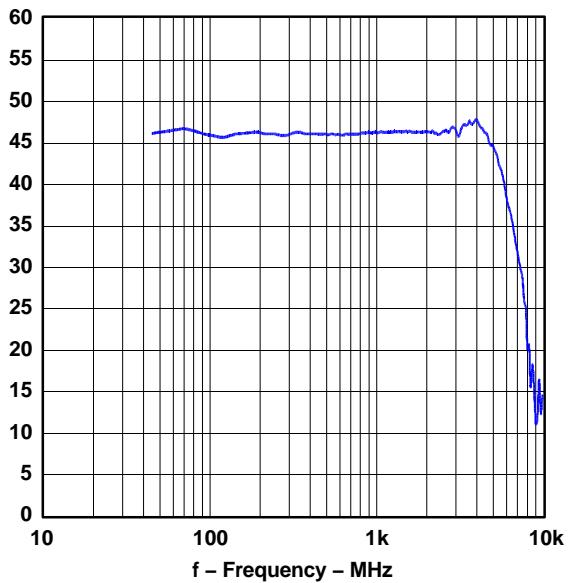


G007

Figure 5.

FREQUENCY RESPONSE

Small Signal Gain – dB



G004

Figure 6.

TYPICAL CHARACTERISTICS (continued)

Typical operating condition is at $V_{CC} = 3.3$ V and $T_A = 25^\circ\text{C}$ (unless otherwise noted).

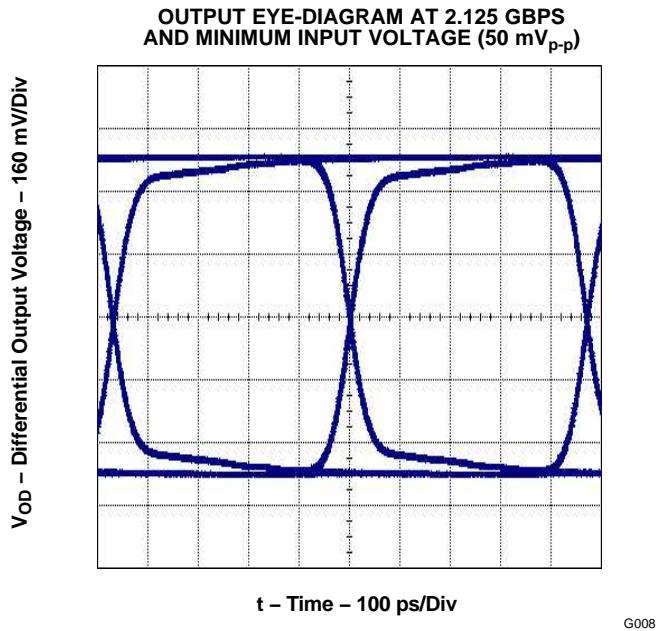


Figure 7.

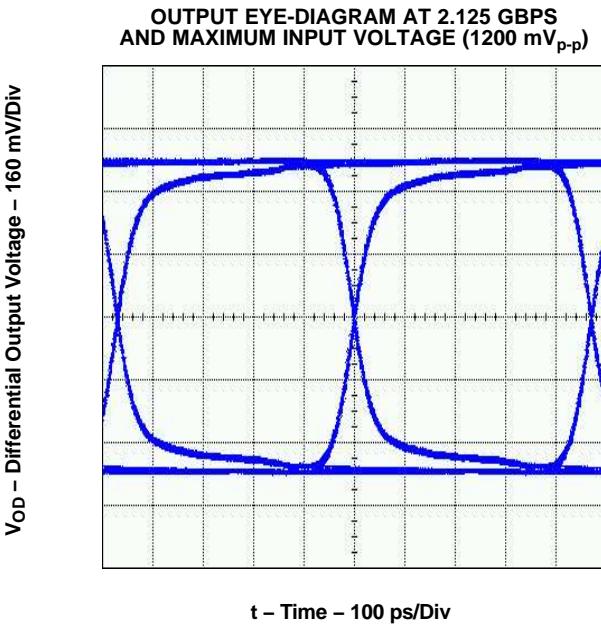


Figure 8.

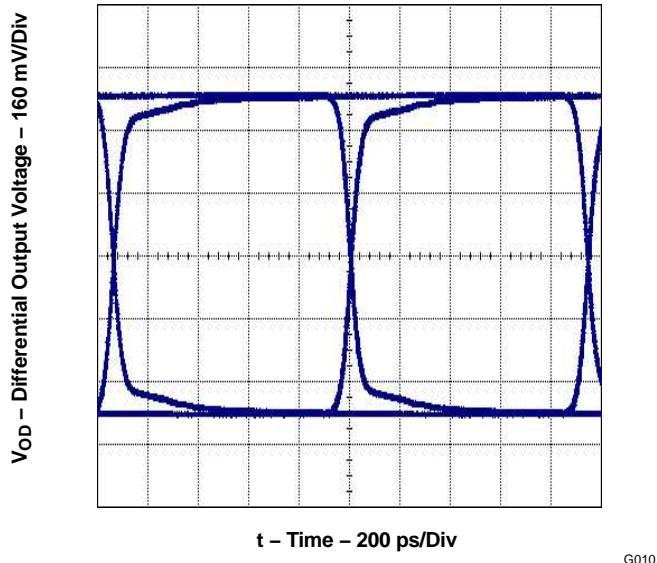


Figure 9.

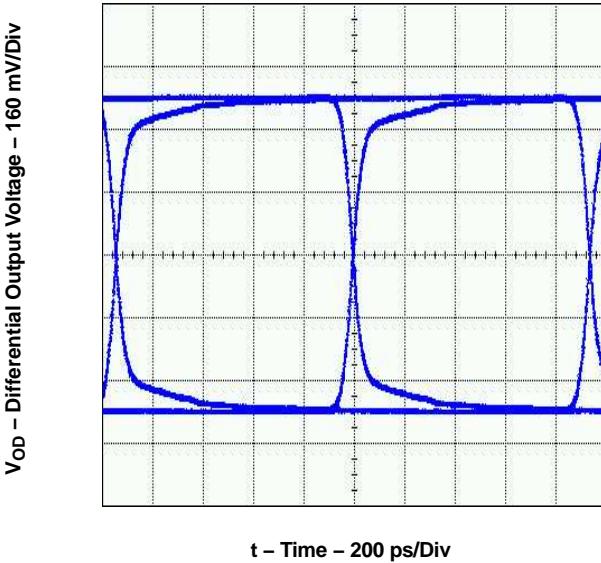


Figure 10.

TYPICAL CHARACTERISTICS (continued)

Typical operating condition is at $V_{CC} = 3.3$ V and $T_A = 25^\circ\text{C}$ (unless otherwise noted).

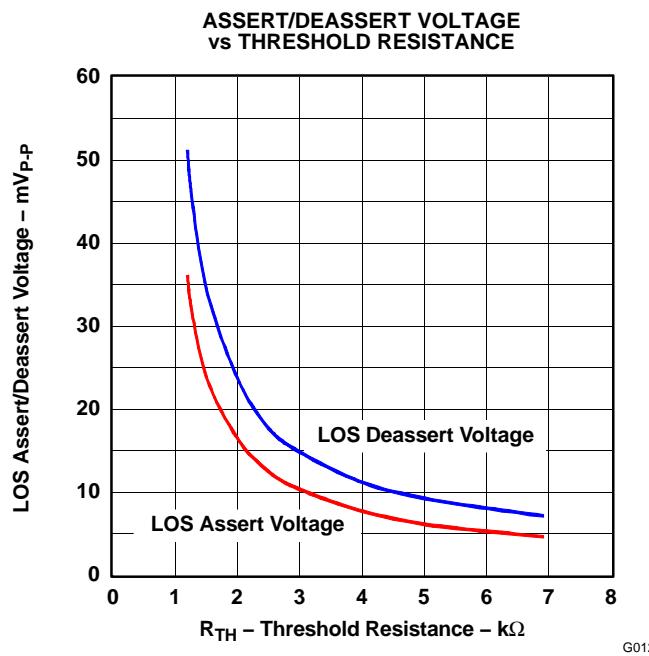


Figure 11.

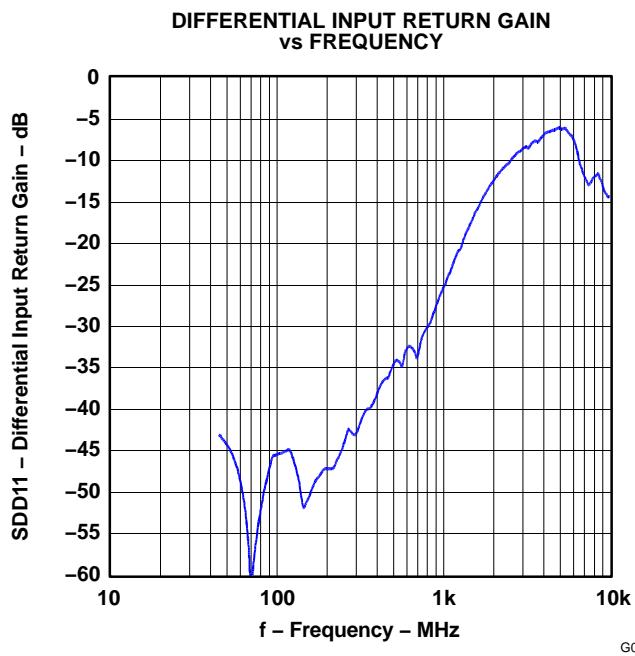


Figure 12.

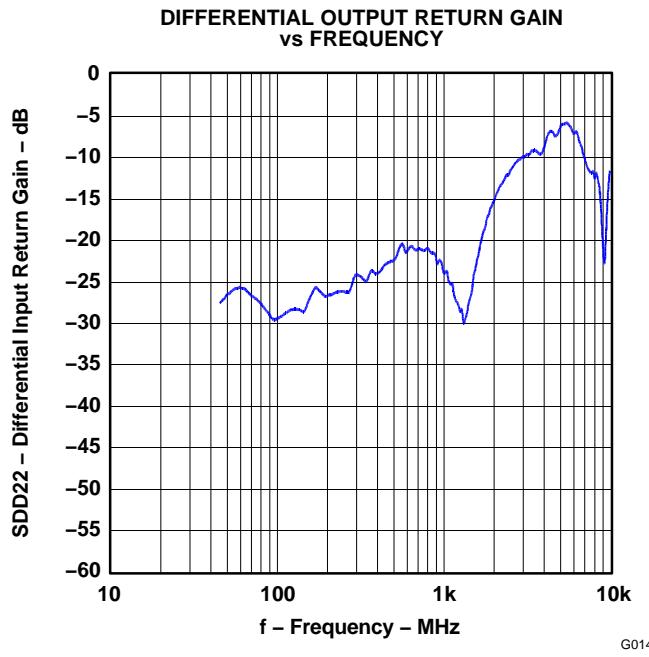


Figure 13.

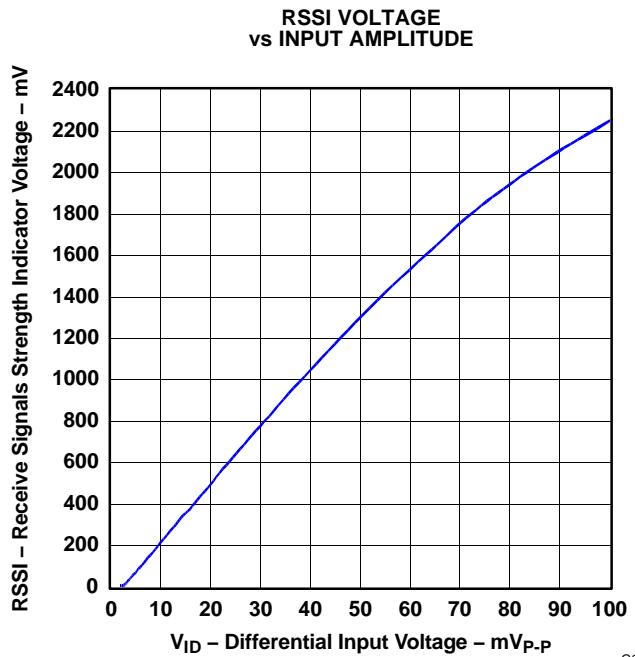


Figure 14.

APPLICATION INFORMATION

Figure 15 shows the ONET4251PA connected with an ac-coupled interface to the data signal source as well as to the output load.

Besides the ac-coupling capacitors C_1 through C_4 in the input and output data signal lines, the only required external component is the LOS threshold setting resistor R_{TH} . In addition, if a low cutoff frequency is required, as an option, an external filter capacitor C_{OC} may be used.

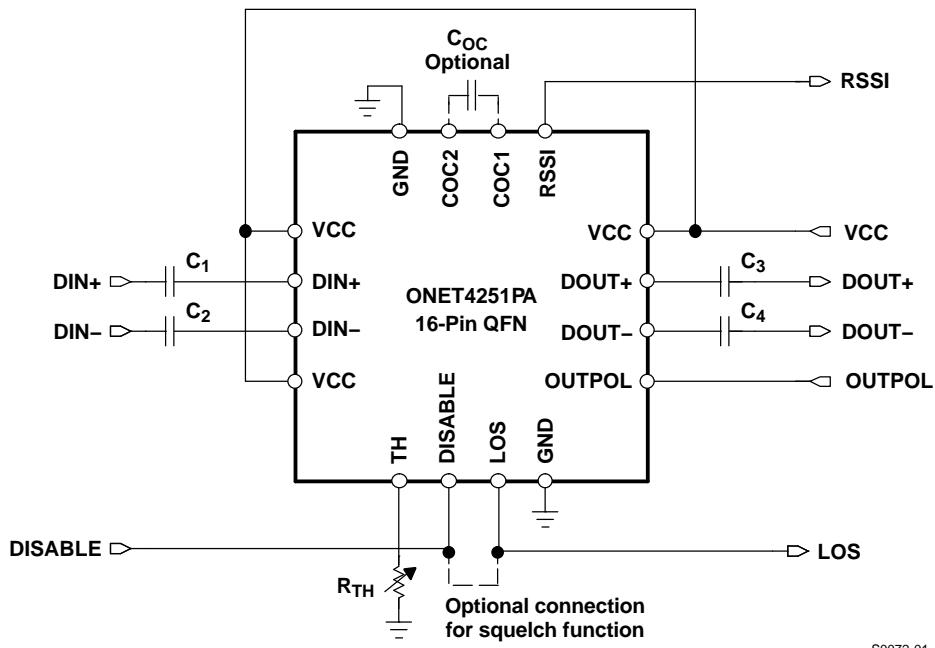


Figure 15. Basic Application Circuit With AC Coupled I/Os

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
ONET4251PARGTT	Obsolete	Production	VQFN (RGT) 16	-	-	Call TI	Call TI	-40 to 85	451P

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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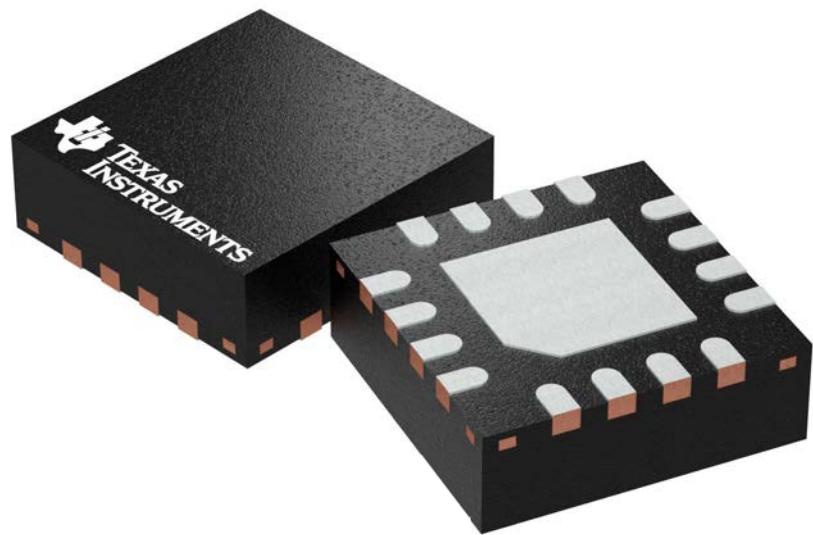
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GENERIC PACKAGE VIEW

RGT 16

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203495/I

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